Specification No.	
Date	

SPECIFICATIONS

MODEL : LEUV-C31A

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Optical Device Business Operation Components Division

UV-LED CHIP

MODEL : LEUV-C31A

	APPLICANT		
Traced by	Checked by	Approved by	
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- Be careful never to exceed , even momentarily, the absolute maximum ratings specified in the data sheet.
- It will not be held responsible for any damage to the user that may result from accidents or any other reasons during operation of the user's unit if use to exceed the absolute maximum ratings, or not keep the matters that demand special attention.

Precautions for use

- ① Be sure to ground the worker's body and equipment when he or she handles the device.
- 2 Do not drop the device or give any other mechanical shock.
- ③ Set the electric potential of the work bench to the same as that of the power supply ground line.
- ④ Store diodes in relative humidity of bellow 70%, and assure that the storage atmosphere is avoid of dust and gases harmful to diodes.
- (5) Use a storage case which can not be easily charged with static electricity.
- (6) This device is designed for general electric equipment.
 - * Computer

- * Measuring instrument
 * Home appliances
- * OA equipment * AV equipment

* Telecommunication equipment(Terminal) etc.

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3. Chip's Physical Structure :

	Substrate	Sapphire
Chin Characteristics	Chip size	0.375 x 0.330 ±0.03mm
Chip Charactensucs	Thickness	$80 \pm 20 \mu m$
	Orientation	(0001) ±0.5 °c-plane

4. Absolute Maximum Rating

Parameter	Symbol	Condition	Unit
Forward Current	If	30	mA
Pulse Forward Current ¹⁾	lfp	100	mA
Reverse Voltage	Vr	5	v
Power Dissipation	Pd	120	mW
Operating Temperature	Topr	- 30 ~ +80	C
Storage Temperature	Tstg	- 40 ~ +100	C

1) Pulse Width<10msec, Duty<1/10

5. Electro-Optical Characteristics :

Electro-Optical Characteristics : (Ta							(Ta=25℃)
Parameter	Syn	nbol	Condition	Min	Тур	Max	Unit
Forward Voltage	1	٧f	If $= 20 \text{mA}$			4.0	v
Reverse current	I	r	Vr = 5.0 V			10	μ A
Dominant Wavelength	1	Wp	If = 20mA	390		405	nm
Luminous Intensity ⁽¹⁾	Iv	A	If = 20mA	2.0			mW

equipment on bare chip. However, the electrical (1) Luminous Intensity is measured by and optical characteristics on lamps made from our chips is not guaranteed.

6. Reliability (Aging Test)

6-1 The reliability criteria of LED chip

Operating condition	Room Temp., If=20mA, 48Hr	
	Vf < Initial values lop x 1.2	
Judgement of failure	Ir < Initial values lop x 1.2	
	lv < Initial values lop x 1.2	

Ass'y Type : TO-18 Header, Without resin coating

6-2 Appearance check

We do appearance check for all chips, and we do not supply chips which will be out of specification according to inspection.

- 6.2.1 Check method : by 2 x 10 or 2 x 20 microscope.
- 6.2.2 Sampling size : 5chips/sheet.
- 6.2.3 Check items : appearance check of top side.
- 6.2.4 Standard : FQC inspection specification.

Description (Top side view)	Figure
Electrode damaged area \leq 1/10 original electrode area.	○ C or ○ C
Particle, dust, remnant area can not be larger than 1/20 emitting area.	
Chip crack damage, underlying damage area must be \leq 25 μ m diameter.	• •
p, n-electrode surface fineness must be uniform.	
Defect shape around the electrode width must be \leq 1 mil.	or C
Contamination in chip can not be larger than 1/10 chip emitting area	
Bottom slip cutting can not be more than 1/10 original bottom area.	(side view)
Inclination of chip angle $\leq \pm 30^{\circ}$ Chip fall down $\leq 2ea / sheet$	
Keep protection paper absolutely clean. Protection paper can not be damaged or scratched.	

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7. Packaging

The chips are packed in paper (5mm thick) boxes after packaging in anti-electrostatic polyethylene bag. According to the total delivery amount, cardboard and air vinyl boxes will be used to protected the wafers from mechanical shocks during transportation. Please refer to bellow figure. The label on the minimum packing unit bag shows ; model number, lot number and quantity with data.

The boxes are not resistant and they must be keep away from water, moisture and dust.

If a box shows noticeable damage upon arrival at the user's warehouse, it is recommended to make a notice within two weeks after arrival of the products.



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8. Lot Number		
The first six digits number shows lot number.		
The lot number is composed of the following character :		
Example : $\triangle \bigtriangledown \bigstar \diamondsuit \diamondsuit \diamondsuit \oslash \diamondsuit \bigcirc$		
riangle abla ee : Kind of device (BL for Blue LED, HR for Hyper	RED)	
★ : Year (M for 2000, M1 for 2001)		
\Rightarrow : Month (Ja for Jan., Se for Sep., Oc for Oct.,	No for Nov.)	
♥ ♥ ♥ ♥ Product Number		
0 Othere		
We cannot take any responsibility for any trouble that are ca chips at conditions exceeding our specifications	used by using t	he
These chips are designed and manufactured for standard a	plications such	as electric
home appliances, communication equipment, office equipm	ent, electronic e	quipment and
requires any particular quality or reliability which concerns	human life. Exa	amples would
be medical equipment, aerospace applications, traffic signal	s, safety system	equipment
and so on.		